

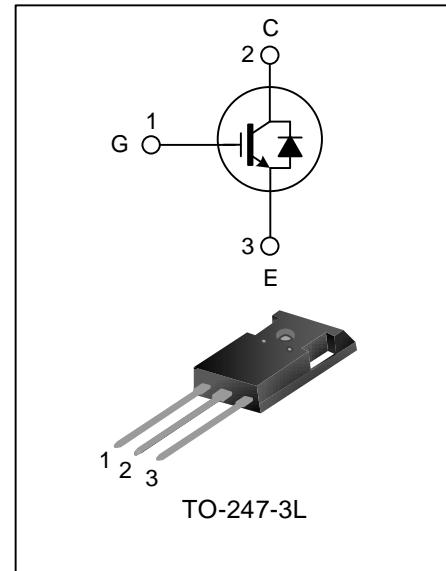
75A, 650V FIELD STOP IGBT

DESCRIPTION

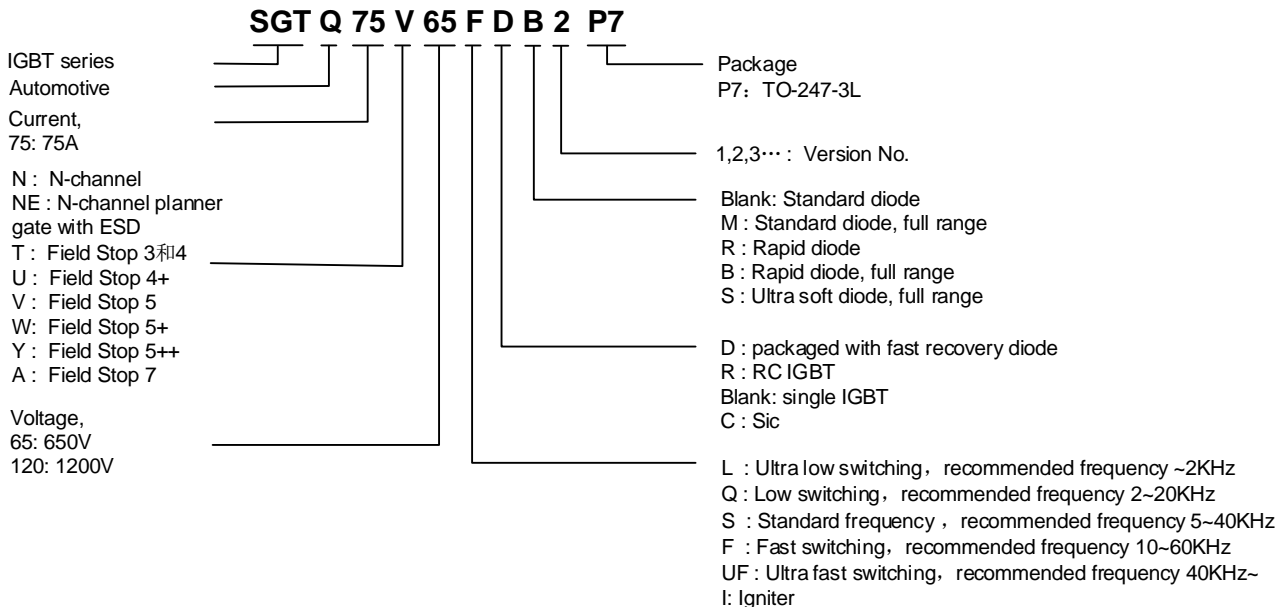
The SGTQ75V65FDB2P7 field stop IGBT adopts Silan Field Stop 5 technology. It features low conduction loss and switching loss, is applicable to photovoltaic, UPS, SMPS and PFC fields.

FEATURES

- ◆ 75A, 650V, $V_{CE(sat)(typ.)}=1.65V@I_C=75A$
- ◆ Low conduction loss
- ◆ Fast switching
- ◆ High input impedance
- ◆ $T_{Jmax}=175^{\circ}C$



NOMENCLATURE



ORDERING INFORMATION

Part No.	Package	Marking	Hazardous Substance Control	Packing Type
SGTQ75V65FDB2P7	TO-247-3L	Q75V65FDB2	Halogen free	Tube

ABSOLUTE MAXIMUM RATINGS (T_C=25°C, UNLESS OTHERWISE NOTED)

Characteristics	Symbol	Ratings	Unit
Collector-emitter Voltage	V _{CE}	650	V
Gate-emitter Voltage	V _{GE}	±20	V
Transient Gate-emitter Voltage (t _p ≤10μs, D<0.010)	V _{GE}	±30	V
Collector Current	I _C	T _C =25°C	150
		T _C =100°C	75
Pulsed Collector Current	I _{CM}	300	A
Diode Forward Current	I _F	T _C =25°C	150
		T _C =100°C	75
Diode Pulse Current	I _{FM}	300	A
Power Dissipation (T _C =25°C)	P _{tot}	375	W
Operating Junction Temperature	T _J	-40~+175	°C
Storage Temperature Range	T _{stg}	-55~+150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Thermal Resistance, Junction to Case (IGBT)	R _{th(j-c)}	--	--	--	0.40	°C/W
Thermal Resistance, Junction to Case (FRD)	R _{th(j-c)}	--	--	--	0.45	°C/W
Thermal Resistance, Junction to Ambient (IGBT)	R _{th(j-a)}	--	--	--	40	°C/W
Soldering Temperature (in line)	T _{sold}	15 ⁺² ₋₀ sec, 1time	--	--	260	°C

ELECTRICAL CHARACTERISTICS OF IGBT (T_C=25°C, UNLESS OTHERWISE NOTED)

Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Collector-emitter Breakdown Voltage	V _{(BR)CES}	V _{GE} =0V, I _C =250μA	650	--	--	V
Zero Gate Voltage Collector Current	I _{CES}	V _{CE} =650V, V _{GE} =0V	--	--	75	μA
Gate-emitter Leakage Current	I _{GES}	V _{GE} =20V, V _{CE} =0V	--	--	±100	nA
Gate-emitter Threshold Voltage	V _{GE(th)}	I _C =250μA, V _{CE} =V _{GE}	3.2	4.0	5.2	V
Collector-emitter Saturation Voltage	V _{CEsat}	I _C =75A, V _{GE} =15V, T _C =25°C	--	1.65	2.2	V
		I _C =75A, V _{GE} =15V, T _C =175°C	--	2.10	--	V
Input Capacitance	C _{ies}	V _{CE} =30V V _{GE} =0V f=1MHz	--	4816	--	pF
Output Capacitance	C _{oes}		--	129	--	
Reverse Transfer Capacitance	C _{res}		--	18	--	
Turn-on Delay Time	T _{d(on)}	V _{CE} =400V I _C =75A R _g =10Ω V _{GE} =15V Inductive load T _C =25°C	--	30	--	ns
Rise Time	T _r		--	31	--	
Turn-off Delay Time	T _{d(off)}		--	190	--	
Fall Time	T _f		--	24	--	
Turn-on Energy	E _{on}	Inductive load T _C =25°C	--	1.68	--	mJ
Turn-off Energy	E _{off}		--	0.76	--	
Total Switching Energy	E _{st}		--	2.44	--	
Turn-on Delay Time	T _{d(on)}	V _{CE} =400V I _C =37.5A R _g =10Ω V _{GE} =15V Inductive load T _C =25°C	--	26	--	ns
Rise Time	T _r		--	18	--	
Turn-off Delay Time	T _{d(off)}		--	190	--	
Fall Time	T _f		--	29	--	
Turn-on Energy	E _{on}	Inductive load T _C =25°C	--	0.69	--	mJ
Turn-off Energy	E _{off}		--	0.31	--	
Total Switching Energy	E _{st}		--	1.00	--	
Total Gate Charge	Q _g	V _{CE} =520V, I _C =75A, V _{GE} =15V	--	179	--	nC
Gate to Emitter Charge	Q _{ge}		--	35	--	
Gate to Collector Charge	Q _{gc}		--	47	--	

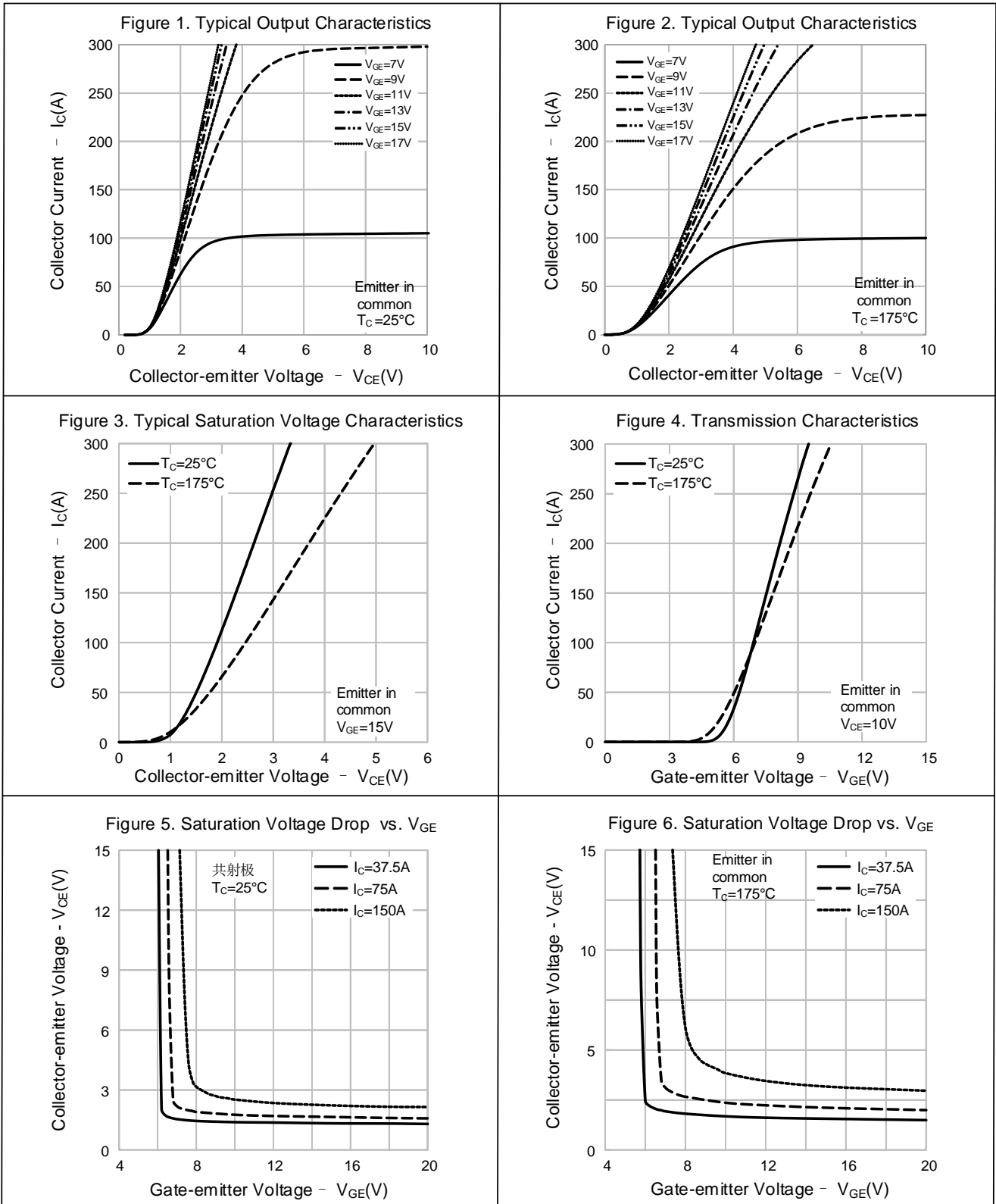
ELECTRICAL CHARACTERISTICS OF FRD (T_C=25°C, UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Diode Forward Voltage	V _F	I _F =75A, T _C =25°C	--	1.60	2.0	V
		I _F =75A, T _C =175°C	--	1.45	--	
Diode Reverse Recovery Time	T _{rr}	I _{ES} =75A, dI _{ES} /dt=200A/μs, V _R =50V, T _C =25°C	--	55	--	ns
Diode Reverse Recovery Charge	Q _{rr}		--	155	--	nC
Diode Peak Reverse Recovery Current	I _{rrm}		--	5.7	--	A

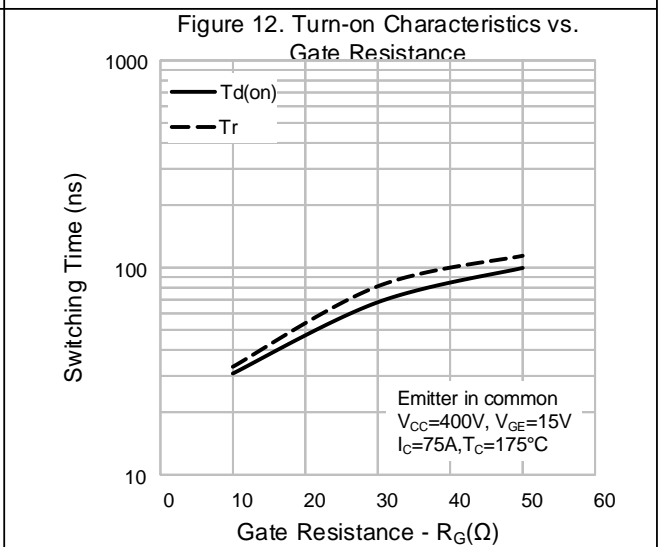
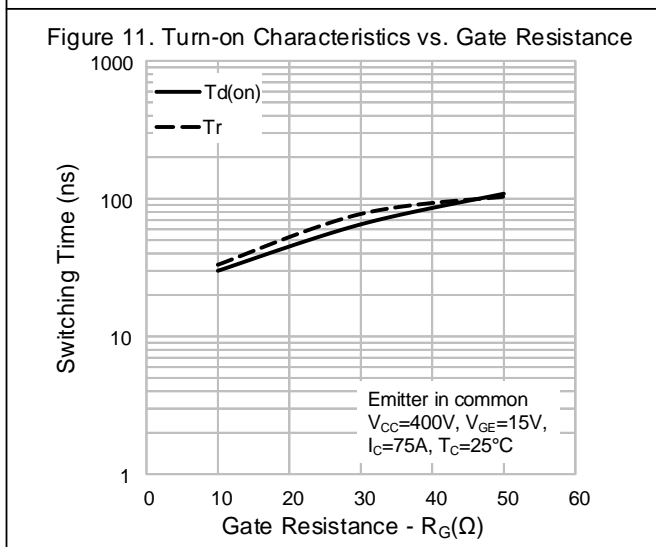
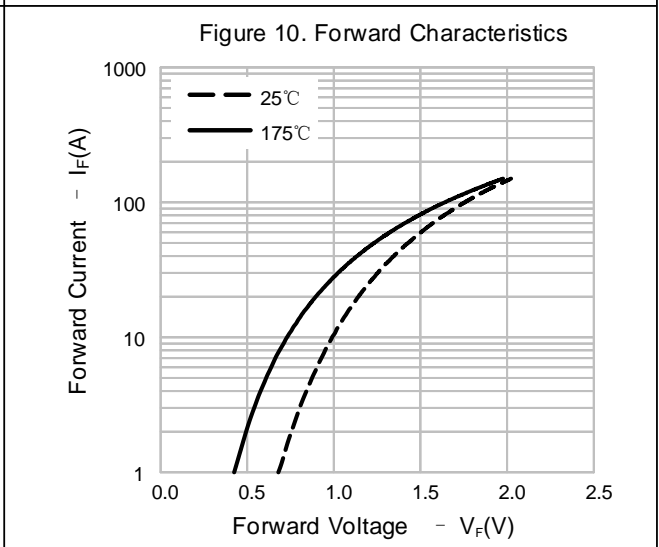
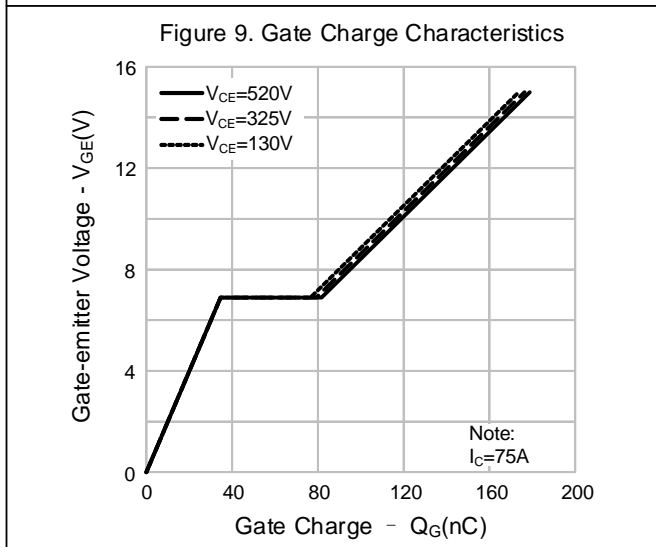
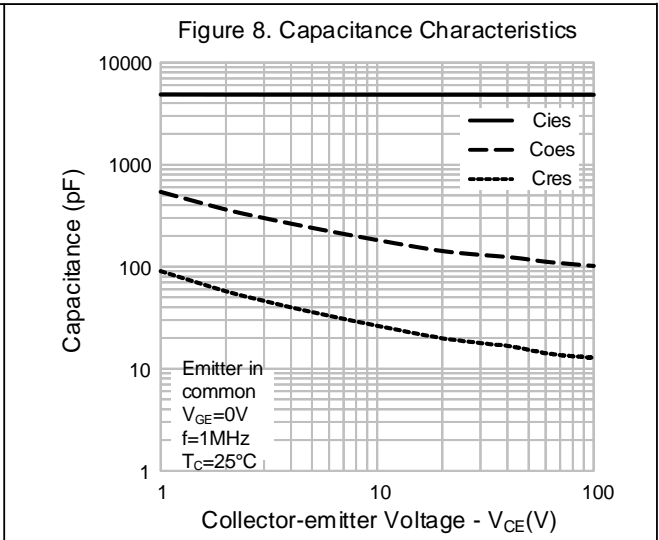
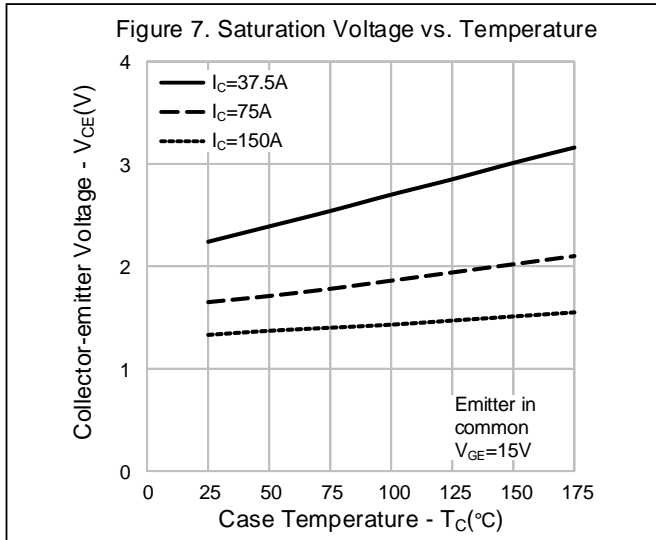
ELECTRICAL CHARACTERISTICS OF IGBT (T_C=175°C)

Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Turn-on Delay Time	T _{d(on)}	V _{CE} =400V I _C =75A R _g =10Ω V _{GE} =15V Inductive load T _C =175°C	--	31	--	ns
Rise Time	T _r		--	33	--	
Turn-off Delay Time	T _{d(off)}		--	233	--	
Fall Time	T _f		--	26	--	
Turn-on Energy	E _{on}	Inductive load T _C =175°C	--	1.91	--	mJ
Turn-off Energy	E _{off}		--	1.24	--	
Total Switching Energy	E _{st}		--	3.15	--	
Turn-on Delay Time	T _{d(on)}	V _{CE} =400V I _C =37.5A R _g =10Ω V _{GE} =15V Inductive load T _C =175°C	--	27	--	ns
Rise Time	T _r		--	20	--	
Turn-off Delay Time	T _{d(off)}		--	234	--	
Fall Time	T _f		--	34	--	
Turn-on Energy	E _{on}	Inductive load T _C =175°C	--	0.81	--	mJ
Turn-off Energy	E _{off}		--	0.51	--	
Total Switching Energy	E _{st}		--	1.32	--	

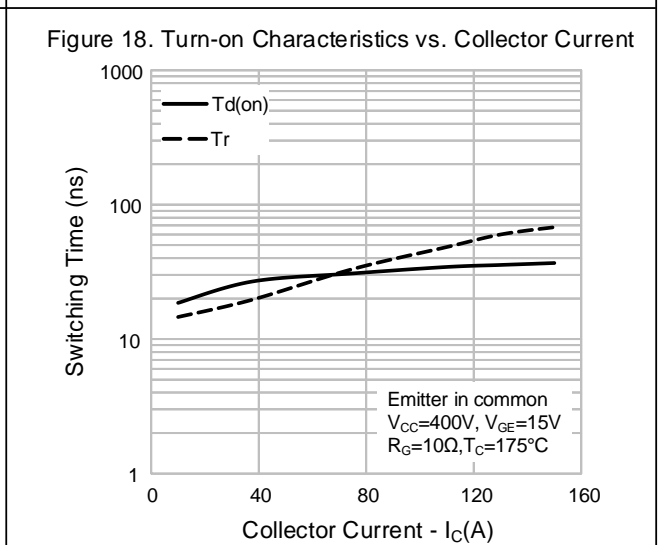
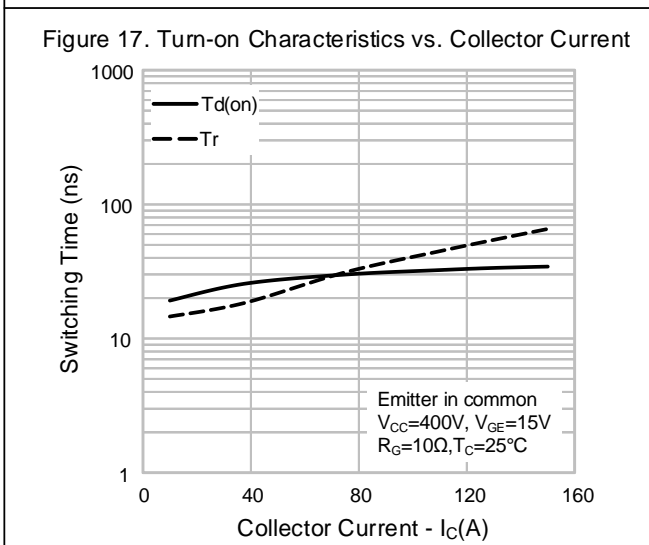
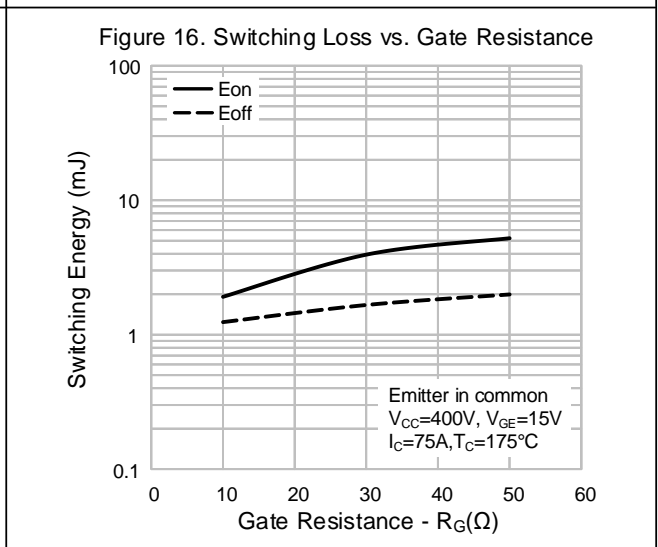
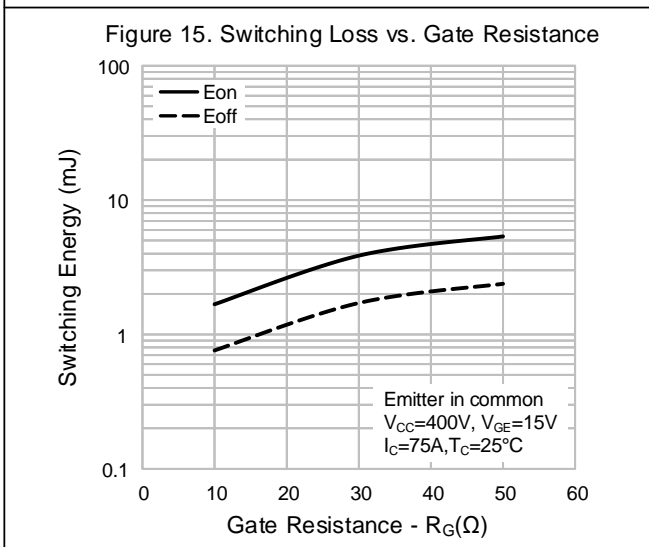
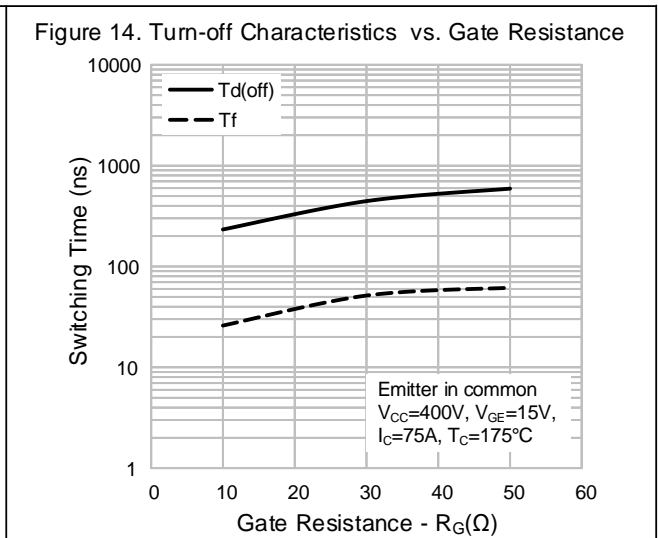
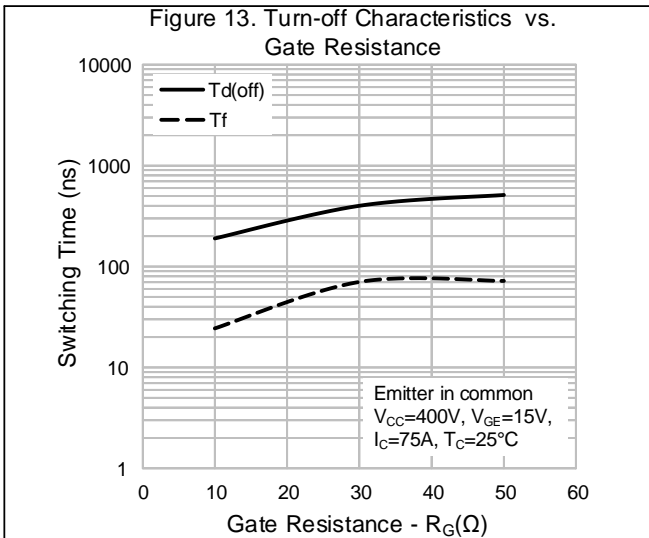
TYPICAL CHARACTERISTICS



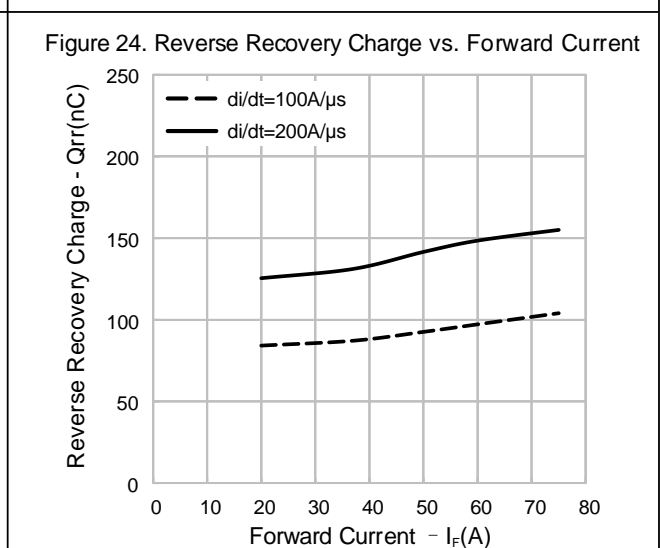
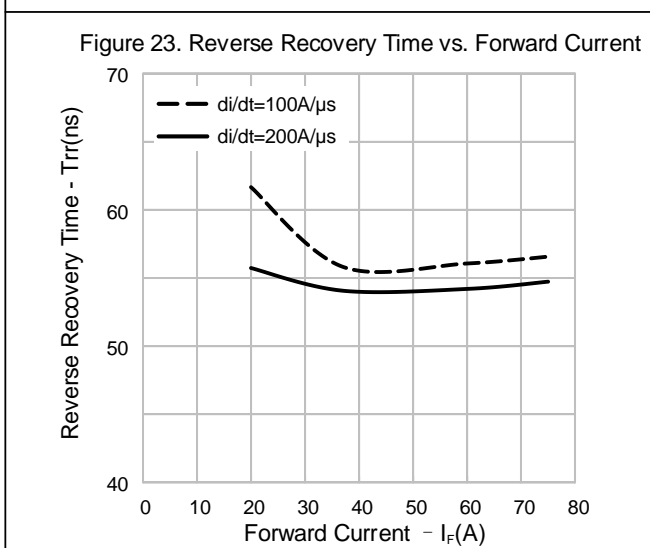
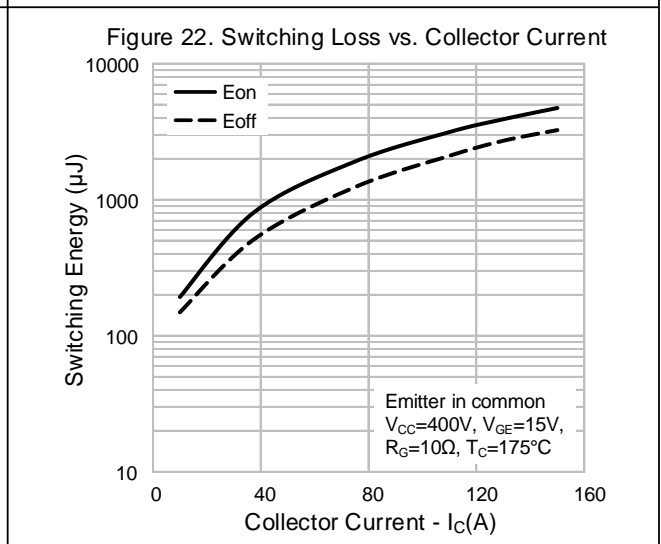
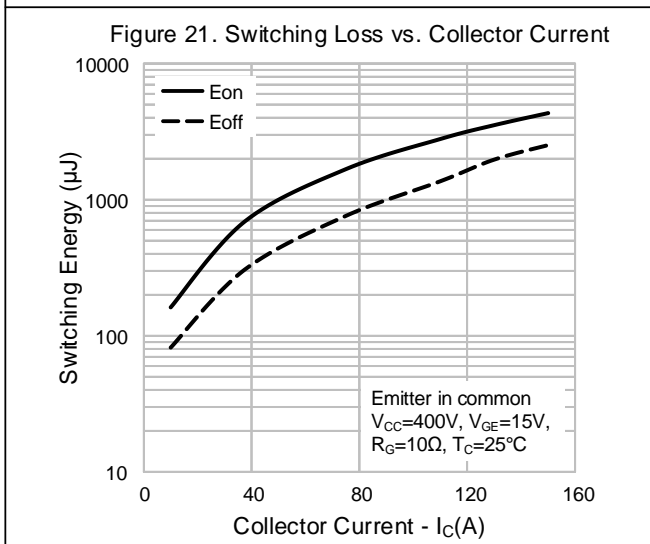
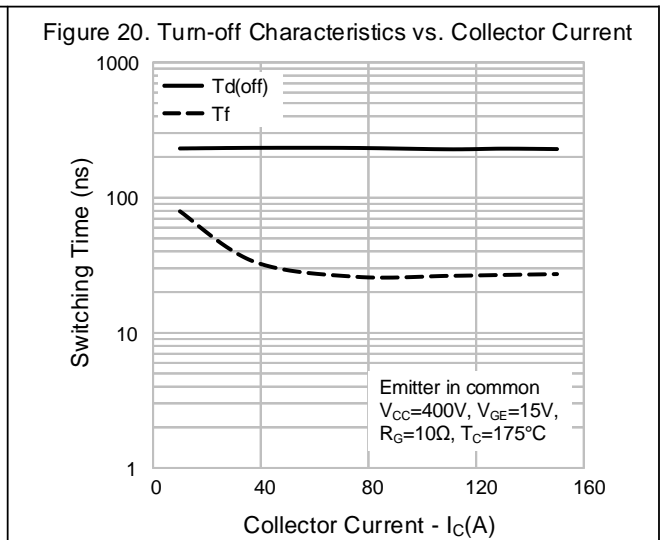
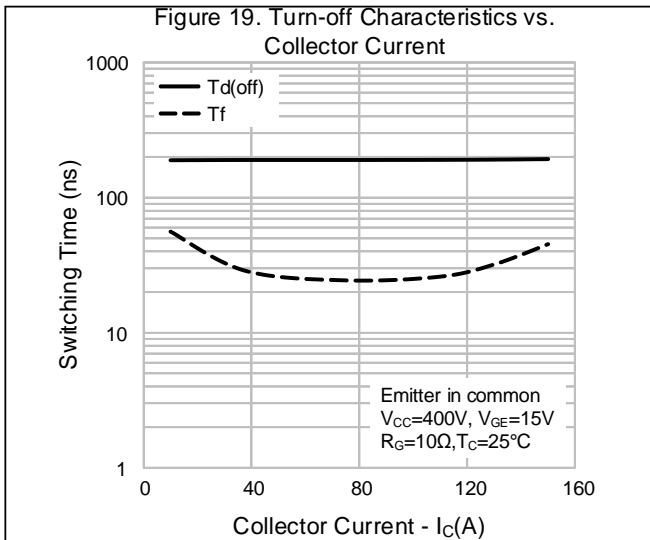
TYPICAL CHARACTERISTICS (CONTINUED)



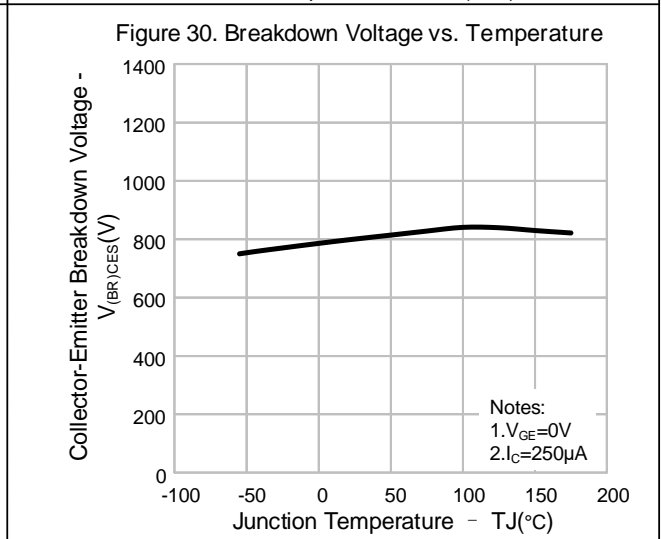
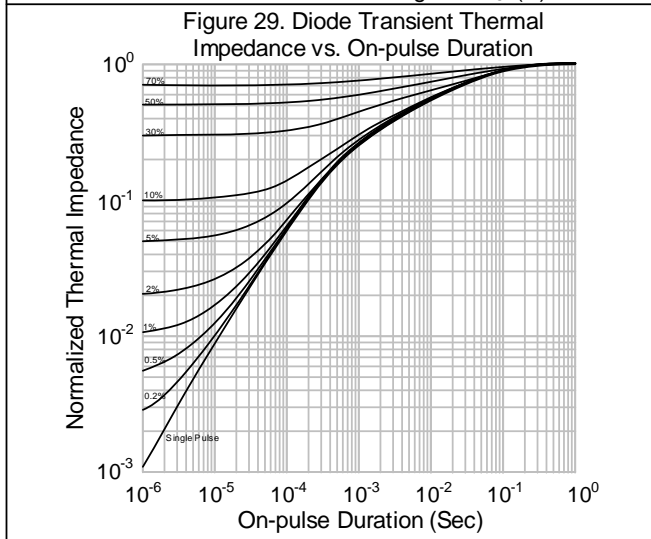
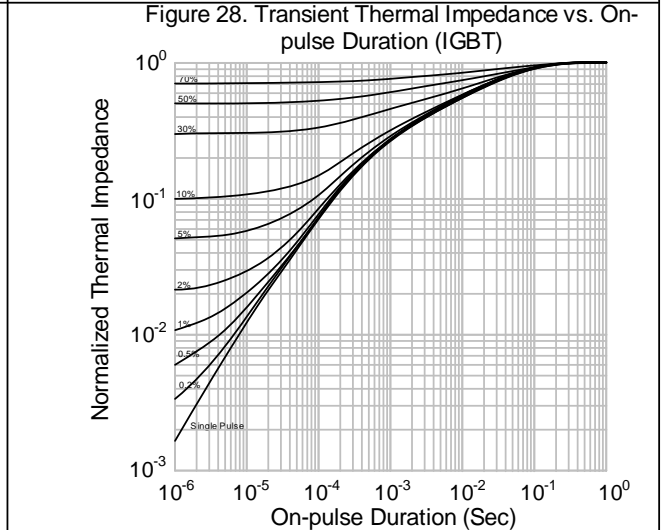
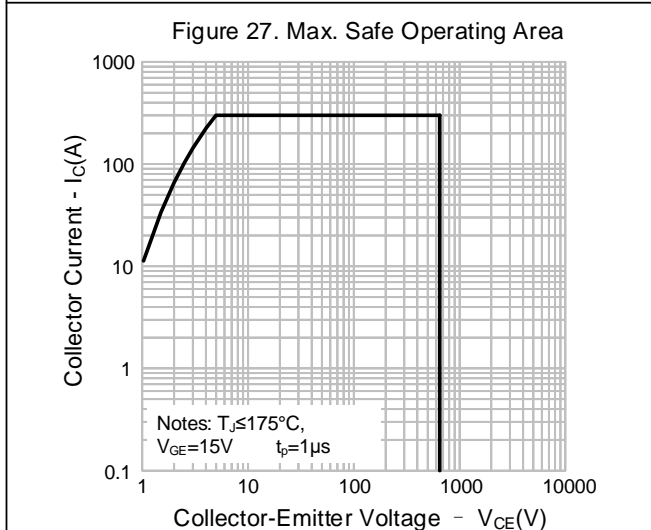
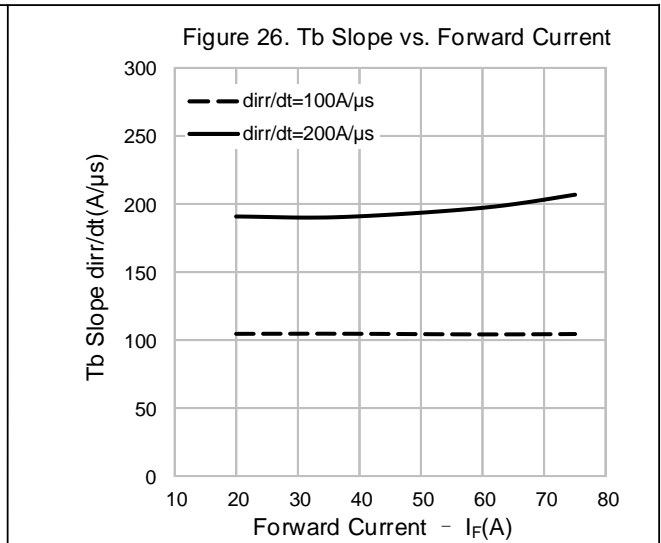
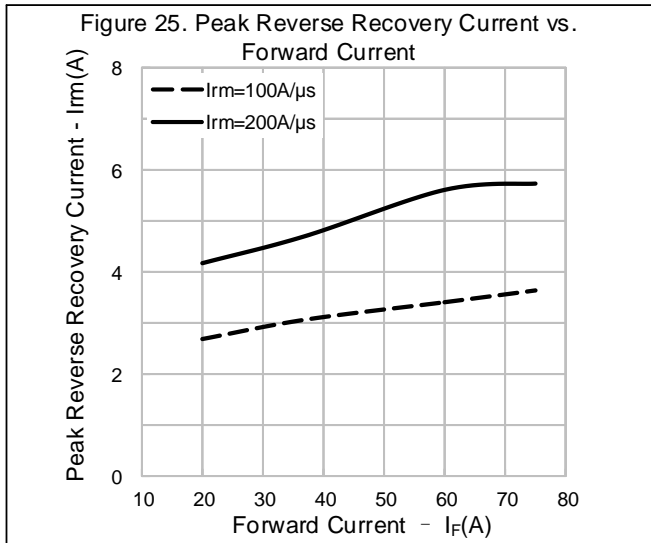
TYPICAL CHARACTERISTICS (CONTINUED)



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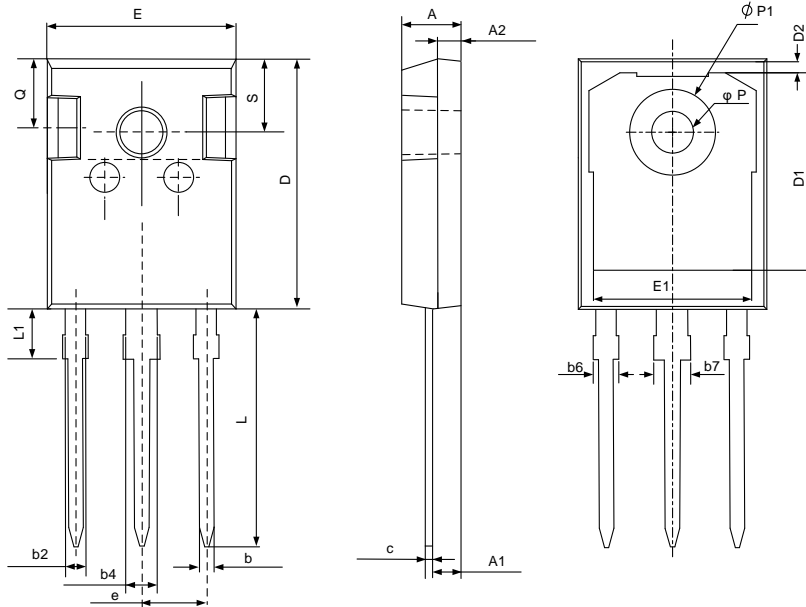
TYPICAL CHARACTERISTICS (CONTINUED)



PACKAGE OUTLINE

TO-247-3L

UNIT: mm



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	4.90	5.00	5.10
A1	2.31	2.41	2.51
A2	1.90	2.00	2.10
b	1.16	1.21	1.26
b2	1.96	—	2.06
b4	2.96	—	3.06
b6	—	—	2.25
b7	—	—	3.25
c	0.59	0.61	0.66
D	20.90	21.00	21.10
D1	16.25	16.55	16.85
D2	1.05	1.20	1.35
E	15.70	15.80	15.90
E1	13.10	13.30	13.50
e	5.44BSC		
L	19.80	19.92	20.10
L1	—	—	4.30
Q	5.60	5.80	6.00
P	3.40	—	3.70
P1	7.00	—	7.40
S	6.15BSC		



IGBT DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the IGBT electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- IGBT devices should be packed in antistatic/conductive containers for transportation.

Important notice:

1. Silan reserves the right to make changes of this instruction without notice.
2. Customers should obtain the latest relevant information when purchasing and should verify whether such information is latest and complete. Please read this instruction and application manual and related materials carefully before using products, including the circuit operation precautions, etc.
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Rev: 1.0

Revision History:

1. First release
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